NPN General - Purpose Amplifier

2N3904

Description

This device is designed as a general-purpose amplifier and switch. The useful dynamic range extends to 100 mA as a switch and to 100 MHz as an amplifier.

MAXIMUM RATINGS

(Values are at $T_A = 25^{\circ}C$ unless otherwise noted.) (Note 1, Note 2)

| Symbol | Parameter | Value | Unit |
|-----------------------------------|---|-------|------|
| V _{CEO} | Collector - Emitter Voltage | 40 | V |
| V _{CBO} | Collector - Base Voltage | 60 | V |
| V _{EBO} | Emitter – Base Voltage | 6.0 | V |
| Ic | Collector Current – Continuous 2 | | mA |
| T _J , T _{STG} | T _{STG} Operating and Storage Junction –55 to +150 Temperature Range | | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. These ratings are based on a maximum junction temperature of 150°C.
- These are steady-state limits. ON Semiconductor should be consulted on applications involving pulsed orlow-duty cycle operations.

THERMAL CHARACTERISTICS

(Values are at T_A = 25°C unless otherwise noted.)

| Symbol | Parameter | Max | Unit |
|----------------|--|------|-------|
| P_{D} | Total Device Dissipation | 625 | mW |
| | Derate Above 25°C | 5.0 | mW/°C |
| $R_{	heta JC}$ | Thermal Resistance, Junction to Case | 83.3 | °C/W |
| $R_{	hetaJA}$ | Thermal Resistance, Junction to Ambient | 200 | °C/W |



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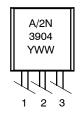




TO-92 3 CASE 135AN

TO-92 3 LEADFORMED CASE 135AR

MARKING DIAGRAM



- 1: Emitter
- 2: Base
- 3: Collector

A = Assembly Code 2N3904 = Device Code YWW = Date Code

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

2N3904

ELECTRICAL CHARACTERISTICS (Values are at T_A = 25°C unless otherwise noted.)

| Symbol | Parametr | Conditions | Min | Max | Unit |
|----------------------|--|---|------|------|------|
| FF CHARACTER | RISTICS | • | • | • | |
| V _{(BR)CEO} | Collector - Emitter Breakdown Voltage | $I_C = 1.0 \text{ mA}, I_B = 0$ | 40 | - | V |
| V _{(BR)CBO} | Collector - Base Breakdown Voltage | $I_C = 10 \mu A, I_E = 0$ | 60 | - | V |
| V _{(BR)EBO} | Emitter – Base Breakdown Voltage | $I_E = 10 \mu A, I_C = 0$ | 6.0 | - | V |
| I _{BL} | Base Cutoff Current | V _{CE} = 30 V, V _{EB} = 3 V | - | 50 | nA |
| I _{CEX} | Collector Cut-Off Current | V _{CE} = 30 V, V _{EB} = 3 V | - | 50 | nA |
| N CHARACTERI | STICS (Note 3) | | | | |
| h _{FE} | DC Current Gain | I _C = 0.1 mA, V _{CE} = 1.0 V | 40 | - | - |
| | | I _C = 1.0 mA, V _{CE} = 1.0 V | 70 | - | |
| | | I _C = 10 mA, V _{CE} = 1.0 V | 100 | 300 | |
| | | $I_C = 50 \text{ mA}, V_{CE} = 1.0 \text{ V}$ | 60 | - | |
| | | I _C = 100 mA, V _{CE} = 1.0 V | 30 | - | |
| V _{CE(sat)} | Collector - Emitter Saturation Voltage | I _C = 10 mA, I _B = 1.0 mA | - | 0.2 | V |
| | | $I_C = 50.0 \text{ mA}, I_B = 5.0 \text{ mA}$ | - | 0.3 | 1 |
| V _{BE(sat)} | Base - Emitter Saturation Voltage | I _C = 10.0 mA, I _B = 1.0 mA | 0.65 | 0.85 | V |
| | | $I_C = 50.0 \text{ mA}, I_B = 5.0 \text{ mA}$ | - | 0.95 | 1 |
| MALL-SIGNAL | CHARACTERISTICS | • | • | • | • |
| f _T | Current - Gain - Bandwidth Product | $I_C = 10 \text{ mA}, V_{CE} = 20 \text{ V},$ f = 100 MHz | 300 | _ | MHz |
| C_{obo} | Output Capacitance | V _{CB} = 5.0 V, I _E = 0, f = 100 kHz | _ | 4.0 | pF |
| C _{ibo} | Input Capacitance | V _{EB} = 0.5 V, I _C = 0, f = 100 kHz | _ | 8.0 | pF |
| NF | Noise Figure | I_C = 100 μA, V_{CE} = 5.0 V, R_S = 1.0 kΩ, f = 10 Hz to 15.7 kHz | - | 5.0 | dB |
| WITCHING CHA | RACTERISTICS | • | _ | - | - |
| t _d | Delay Time | V _{CC} = 3.0 V, V _{BE} = 0.5 V, I _C = 10 mA, I _{B1} = 1.0 mA | - | 35 | ns |
| t _r | Rise Time | | - | 35 | ns |
| t _s | Storage Time | V _{CC} = 3.0 V, I _C = 10 mA, I _{B1} = I _{B2} = 1.0 mA | - | 200 | ns |
| t _f | Fall Time | | _ | 50 | ns |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Pulse Test: Pulse Width ≤ 300 μs; Duty Cycle ≤ 2%.

2N3904

TYPICAL PERFORMANCE CHARACTERISTICS

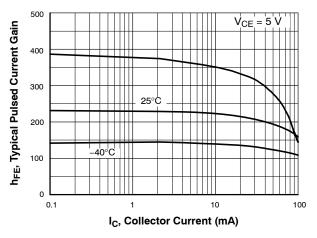


Figure 1. Typical Pulsed Current Gain vs. Collector Current

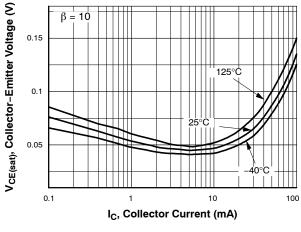


Figure 2. Collector-Emitter Saturation Voltage vs. Collector Current

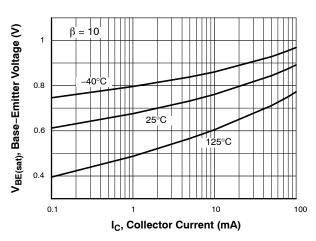


Figure 3. Base–Emitter Saturation Voltage vs. Collector Current

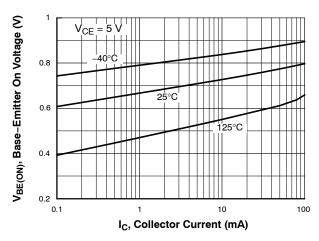


Figure 4. Base-Emitter On Voltage vs. Collector Current

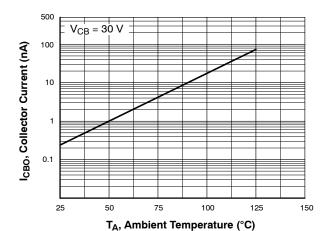


Figure 5. Collector Cut-Off Current vs. Ambient Temperature

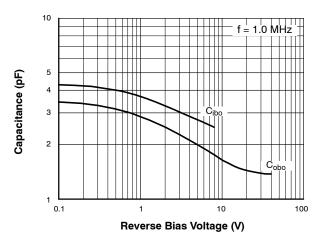


Figure 6. Capacitance vs. Reverse Bias Voltage

TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

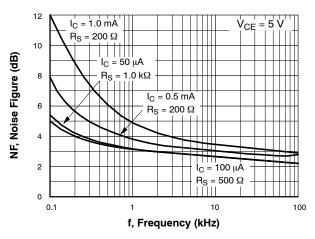


Figure 7. Noise Figure vs. Frequency

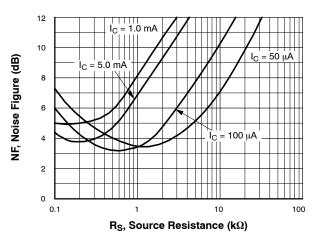


Figure 8. Noise Figure vs. Source Resistance

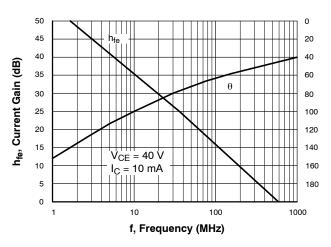


Figure 9. Current Gain and Phase Angle vs. Frequency

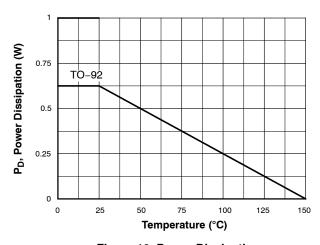


Figure 10. Power Dissipation vs. Ambient Temperature

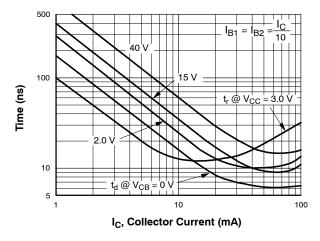


Figure 11. Turn-On Time vs. Collector Current

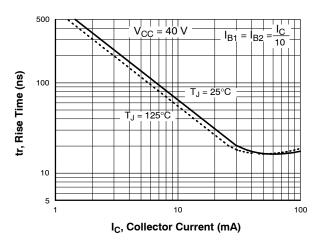


Figure 12. Rise Time vs. Collector Current

TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

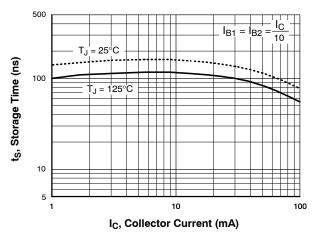


Figure 13. Storage Time vs. Collector Current

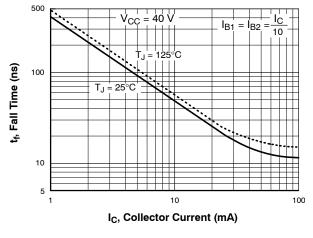


Figure 14. Fall Time vs. Collector Current

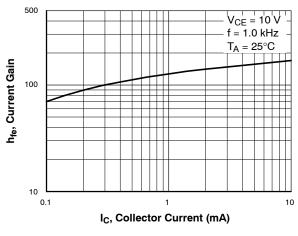


Figure 15. Current Gain

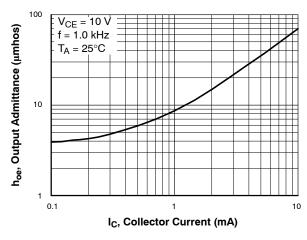


Figure 16. Output Admittance

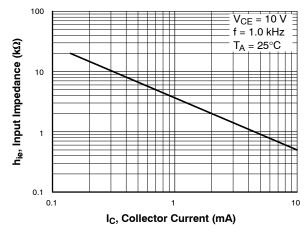


Figure 17. Input Impedance

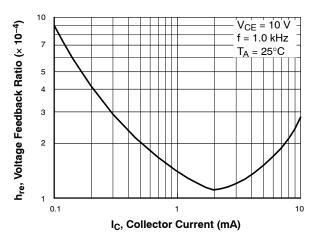


Figure 18. Voltage Feedback Ratio

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TEST CIRCUITS

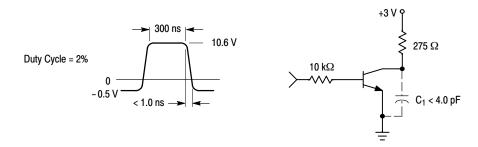


Figure 19. Delay and Rise Time Equivalent Test Circuit

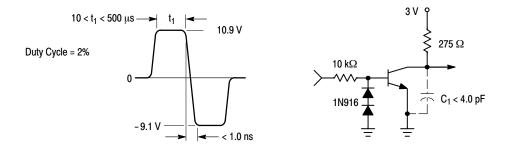


Figure 20. Storage and Fall Time Equivalent Test Circuit

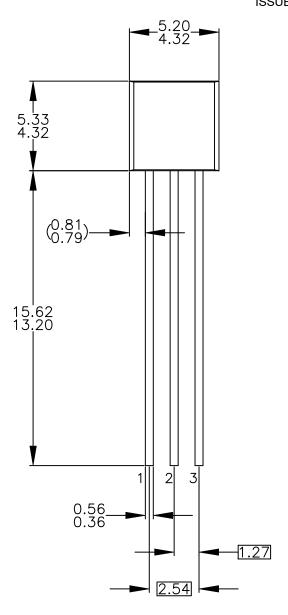
ORDERING INFORMATION

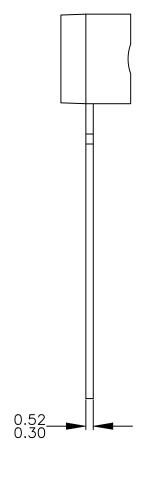
| Device | Package | Shipping [†] |
|-----------|-------------------------|--------------------------|
| 2N3904BU | TO-92-3 LF (Pb-Free) | 10000 Units / Bulk Bag |
| 2N3904TA | TO-92-3 LF (Pb-Free) | 2000 Units / Fan-Fold |
| 2N3904TAR | TO-92-3 LF (Pb-Free) | 2000 Units / Fan-Fold |
| 2N3904TF | TO-92-3 LF (Pb-Free) | 2000 Units / Tape & Reel |
| 2N3904TFR | TO-92-3 LF (Pb-Free) | 2000 Units / Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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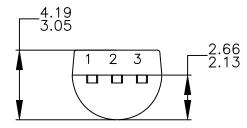
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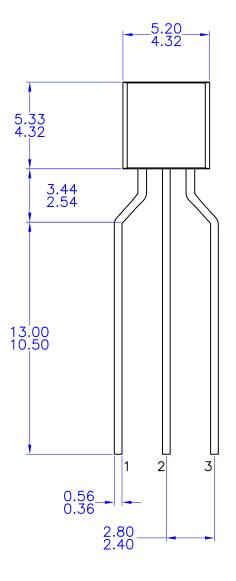
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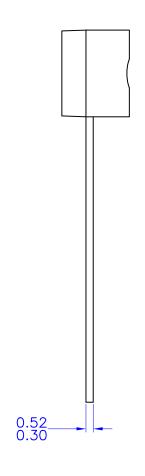
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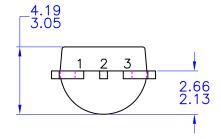
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